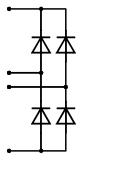
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Silicon Carbide Schottky Rectifier Bridge in ISOPLUS i4-PAC[™] FBS 16-06SC





Features

Silicon Carbide Schottky Diodes

- no reverse recovery at turn off only charge of junction capacity - soft turn off waveform
- no forward recovery at turn on
- switching behaviour independent of temperature
- low leakage current
- ISOPLUS i4-PAC(TM) package
- isolated back surface
- low coupling capacity between pins and heatsink
- enlarged creepage towards heatsinkapplication friendly pinout
- bigh reliability
- high reliability
- industry standard outline

Applications

- output rectifiers of high end switched mode power supplies
- other high frequency rectifiers

Rectifier Bridge

Symbol	Conditions		Maximum Ra	Maximum Ratings		
V _{RRM}			600	V		
I _{fav} I _{d(av)m} I _{fsm}	$T_c = 90^{\circ}C$	180° (per diode) 0 ms; sine 50 Hz	5 11 20	A A A		
P _{tot}	$T_c = 25^{\circ}C$	(per diode)	27	W		

Symbol	Conditions Characteristic $(T_{yJ} = 25^{\circ}C, unless)$			aracteristic Values otherwise specified)		
			min.	typ.	max.	
V _F	I _F = 6 A;	$T_{VJ} = 25^{\circ}C$ $T_{VJ} = 125^{\circ}C$		1.5 1.6	1.8	V V
I _R	$V_{R} = V_{RRM};$	$T_{VJ} = 25^{\circ}C$ $T_{VJ} = 125^{\circ}C$		0.05	0.2	mA mA
C ¹	V _R = 400 V;	$T_{VJ} = 125^{\circ}C$		21		pF
R _{thJC} R _{thJS}	(per diode)			8.6	5.6	K/W K/W

Data according to IEC 60747 and refer to a single diode unless otherwise stated.

IXYS reserves the right to change limits, test conditions and dimensions.

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Weight

Component							
Symbol	Conditions	Γ	Maximum Ratings				
T _{vj} T _{stg}		-	55+17 55+12				
V	I _{ISOL} ≤ 1 mA; 50/60 Hz		2500				
F _c	mounting force with clip		20120				
Symbol	Conditions	Characteristic Values min. typ. max.					
C _p	coupling capacity between shorted pins and mounting tab in the case		40	pF			
d _s ,d _A d _s ,d _A	pin - pin pin - backside metal	1.7 5.5		mm mm			

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g

